

1. Features

- Typical 1dB bandwidth of 18.9 MHz
- High attenuation
- Single Ended Operation
- Dual In-line Package (DIP)

RoHS Compliant

Tested by SGS Testing Korea

2. Electrical Specifications

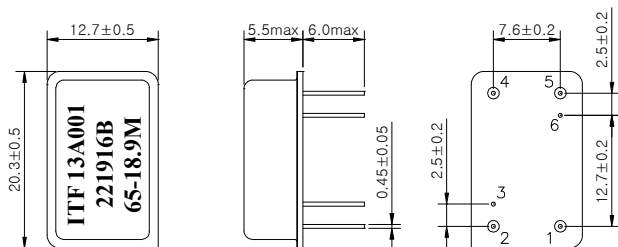
Source and Load Impedance = 50Ω

Room Temperature : +25°C

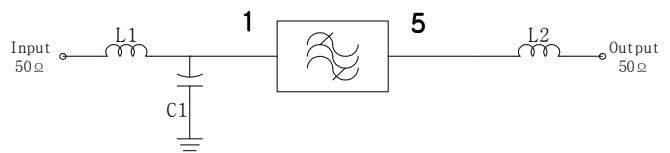
		Minimum	Typical	Maximum
Center Frequency (fo)	MHz	64.93	65.0	65.07
Insertion Loss	dB	-	23.5	25.0
1dB Bandwidth	MHz	18.80	18.90	-
3dB Bandwidth	MHz	-	19.18	-
45dB Bandwidth	MHz	-	20.48	20.60
Amplitude Ripple	dB	-	0.5	1.2
Group Delay Variation	nsec	-	35	80
Absolute Delay	usec	-	2.26	2.3
Ultimate Rejection	dB	50	53	-
Temperature Coefficient of Frequency	ppm/°C	-	-72	-
Substrate Material	-		128-LN	

* Input POWER : 10dBm

D2012 Package Dimension



Matching Schematic



L1 = 150nH, L2 = 150nH, C1 = 2pF

Pin Configuration

Pin Configuration			
Input	1	Ground	2, 4
Output	5	Others	Ground

Dimensions shown are nominal in millimeters

Base : Fe(SPCC), Au plating over Ni plated
Cap : Cu & Cr Alloy, Ni Plated
Termination : Kovar, Au Plated

3. Typical Performance (at +25°C)

